

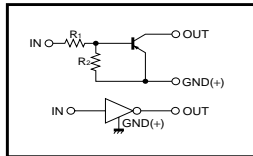
Digital transistor (built-in resistors)

DTA144VUA / DTA144VKA / DTA144VSA

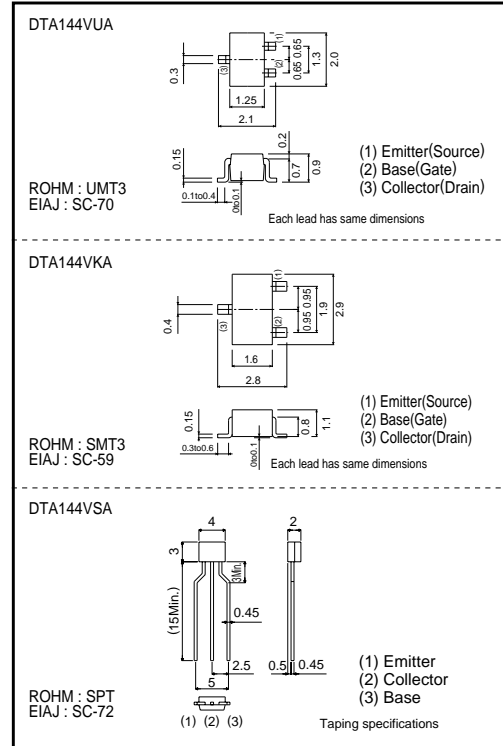
●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making device design easy.
- 4) Higher mounting densities can be achieved.

●Equivalent circuit



●External dimensions (Units : mm)



●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	-50	V
Input voltage	V _I	-40~+15	V
Output current	I _O	-30	mA
	I _{C(Max.)}	-10	
Power dissipation	DTA144VUA / DTA144VKA DTA144VSA	P _d	200
		300	mW
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-55~+150	°C

●Packaging, marking and packaging specifications

Type	DTA144VUA	DTA144VKA	DTA144VSA
Package	UMT3	SMT3	SPT
Marking	156	E56	-
Packaging code	T106	T146	TP
Basic ordering unit (pieces)	3000	3000	5000

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{I(off)}	-	-	-1	V	V _{CC} =-5V, I _O =-100μA
	V _{I(on)}	-6	-	-		V _O =-0.3V, I _O =-2mA
Output voltage	V _{O(on)}	-	-0.1	-0.3	V	I _O =-10mA, I _I =-0.5mA
Input current	I _I	-	-	-0.16	mA	V _I =-5V
Output current	I _{O(off)}	-	-	-0.5	μA	V _{CC} =-50V, V _I =0V
DC current gain	G _I	33	-	-	-	I _O =-5mA, V _O =-5V
Input resistance	R _I	32.9	47	61.1	kΩ	-
Resistance ratio	R ₂ /R ₁	0.17	0.21	0.26	-	-
Transition frequency	f _T	-	250	-	MHz	V _{CE} =-10V, I _E =5mA, f=100MHz

* Transition frequency of the device.